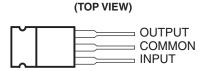


# LOW-DROPOUT VOLTAGE REGULATORS

Check for Samples: TL750M SERIES

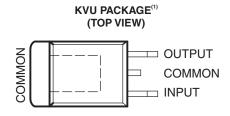
#### **FEATURES**

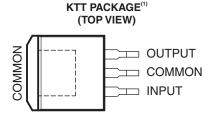
- Low Dropout Voltage, Less Than 0.6 V at 750 mΔ
- Low Quiescent Current
- 60-V Load-Dump Protection



KCS PACKAGE(1)

- Overvoltage Protection
- Internal Thermal-Overload Protection
- Internal Overcurrent-Limiting Circuitry





(1) The common terminal is in electrical contact with the mounting base.

#### **DESCRIPTION/ORDERING INFORMATION**

The TL750M series devices are low-dropout positive voltage regulators specifically designed for battery-powered systems. The TL750M devices incorporate onboard overvoltage and current-limiting protection circuitry to protect the devices and the regulated system. The devices are fully protected against 60-V load-dump and reverse-battery conditions. Extremely low quiescent current, even during full-load conditions, makes the TL750M series ideal for standby power systems.

The TL750M offers 5-V, 8-V, 10-V, and 12-V options. The devices are characterized for operation over the virtual junction temperature range 0°C to 125°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





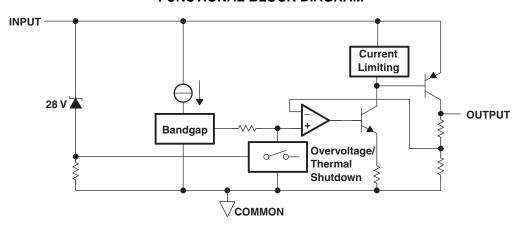
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# ORDERING INFORMATION(1)

TJ	V <sub>O</sub> TYP	PACKAG	E <sup>(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
		PowerFLEX™ – KVU	Reel of 3000	TL750M05CKVUR	750M05C
	5 V	TO-220 - KCS	Tube of 50	TL750M05CKCS	TL750M05C
		TO-263 – KTT	Reel of 500	TL750M05CKTTR	TL750M05C
	8 V	TO-220 – KCS	Tube of 50	TL750M08CKCS	TL750M08C
0°C to 125°C		PowerFLEX – KVU	Reel of 3000	TL750M08CKVUR	750M08C
	10.1/	TO-220 – KCS	Tube of 50	TL750M10CKCS	TL750M10C
	10 V	PowerFLEX – KVU	Reel of 3000	TL750M10CKVUR	750M10C
	12.\/	TO-220 - KCS	Tube of 50	TL750M12CKCS	TL750M12C
	12 V	PowerFLEX – KVU	Reel of 3000	TL750M12CKVUR	750M12C

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

#### **FUNCTIONAL BLOCK DIAGRAM**





# **ABSOLUTE MAXIMUM RATINGS(1)**

over virtual junction temperature range (unless otherwise noted)

			MIN	MAX	UNIT
	Continuous input voltage			26	V
	Transient input voltage (see Figure 3)			60	V
	Continuous reverse input voltage			-15	V
	Transient reverse input voltage	t = 100 ms		-50	V
		KCS package		22	
$\theta_{JA}$	Package thermal impedance (2) (3)	KTT package		25.3	°C/W
		KVU package		28	
$T_{J}$	Virtual-junction temperature range		0	150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Maximum power dissipation is a function of T<sub>J</sub>(max), θ<sub>JA</sub>, and T<sub>A</sub>. The maximum allowable power dissipation at any allowable ambient temperature is P<sub>D</sub> = (T<sub>J</sub>(max) T<sub>A</sub>)/θ<sub>JA</sub>. Operating at the absolute maximum T<sub>J</sub> of 150°C can affect reliability. Due to variation in individual device electrical characteristics and thermal resistance, the built-in thermal-overload protection may be activated at power levels slightly above or below the rated dissipation.
- (3) The package thermal impedance is calculated in accordance with JESD 51.

#### THERMAL INFORMATION

	THERMAL METRIC (1)(2)		LINITO		
	THERMAL METRIC	KCS (3 PINS)	UNITS		
$\theta_{JA}$	Junction-to-ambient thermal resistance	28.7	50.9	27.5	
$\theta_{JCtop}$	Junction-to-case (top) thermal resistance	59.8	57.9	43.2	
$\theta_{JB}$	Junction-to-board thermal resistance	0.5	34.8	17.3	°C/W
ΨЈТ	Junction-to-top characterization parameter	5.3	6	2.8	3C/VV
ΨЈВ	Junction-to-board characterization parameter	0.4	23.7	9.3	
$\theta_{JCbot}$	Junction-to-case (bottom) thermal resistance	0.1	0.4	0.3	

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- (2) For thermal estimates of this device based on PCB copper area, see the TI PCB Thermal Calculator.

#### RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
.,	Input voltage TL750M08	TL750M05	6	26	
		TL750M08	9	26	V
VI		TL750M10	11	26	V
		TL750M12	13	26	
Io	Output current		750	mA	
$T_J$	Operating virtual-junction temperature		0	125	°C



### TL750M05 ELECTRICAL CHARACTERISTICS(1)

 $V_I = 14 \text{ V}, I_O = 300 \text{ mA}, T_J = 25^{\circ}\text{C}$  (unless otherwise noted)

DADAMETED	TEST CONDITIONS	TI	TL750M05				
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
Output voltage		4.95	5	5.05	V		
Output voltage	$T_J = 0$ °C to 125°C	4.9		5.1	V		
lanut valtana nasulatian	$V_1 = 9 \text{ V to } 16 \text{ V}, I_0 = 250 \text{ mA}$		10	25	\/		
Input voltage regulation	$V_1 = 6 \text{ V to } 26 \text{ V}, I_0 = 250 \text{ mA}$		12	50	mV		
Ripple rejection	V <sub>I</sub> = 8 V to 18 V, f = 120 Hz	50	55		dB		
Output regulation voltage	I <sub>O</sub> = 5 mA to 750 mA		20	50	mV		
Dranaut valtage	$I_0 = 500 \text{ mA}$			0.5	V		
Dropout voltage	$I_0 = 750 \text{ mA}$			0.6	V		
Output noise voltage	f = 10 Hz to 100 kHz		500		μV		
Dies sument	I <sub>O</sub> = 750 mA		60	75	A		
Bias current	I <sub>O</sub> = 10 mA			5	mA		

<sup>(1)</sup> Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF tantalum capacitor on the output, with equivalent series resistance within the guidelines shown in Figure 1.

# TL750M08 ELECTRICAL CHARACTERISTICS(1)

 $V_1 = 14 \text{ V}$ ,  $I_0 = 300 \text{ mA}$ ,  $T_1 = 25^{\circ}\text{C}$  (unless otherwise noted)

DADAMETED	TEST COMPITIONS	TL	TL750M08				
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
Output valtage		7.92	8	8.08	V		
Output voltage	$T_J = 0$ °C to 125°C	7.84		8.16	V		
Input voltage regulation	$V_{I} = 10 \text{ V to } 17 \text{ V}, I_{O} = 250 \text{ mA}$		12	40	\/		
	$V_I = 9 \text{ V to } 26 \text{ V}, I_O = 250 \text{ mA}$		15	68	mV		
Ripple rejection	V <sub>I</sub> = 11 V to 21 V, f = 120 Hz	50	55		dB		
Output regulation voltage	I <sub>O</sub> = 5 mA to 750 mA		24	80	mV		
Dropout voltage	I <sub>O</sub> = 500 mA			0.5	V		
Dropout voltage	I <sub>O</sub> = 750 mA			0.6	V		
Output noise voltage	f = 10 Hz to 100 kHz		500		μV		
Diag gurrant	I <sub>O</sub> = 750 mA		60	75	m Λ		
Bias current	I <sub>O</sub> = 10 mA			5	mA		

<sup>(1)</sup> Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF tantalum capacitor on the output, with equivalent series resistance within the guidelines shown in Figure 1.



### TL750M10 ELECTRICAL CHARACTERISTICS(1)

 $V_I = 14 \text{ V}, I_O = 300 \text{ mA}, T_J = 25^{\circ}\text{C}$  (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TI	_750M10		UNIT	
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNII	
Output voltage		9.9	10	10.1	V	
Output voltage	$T_J = 0$ °C to 125°C	9.8		10.2	V	
Input voltage regulation	V <sub>I</sub> = 12 V to 18 V, I <sub>O</sub> = 250 mA		15	43	m) /	
	$V_I = 11 \text{ V to } 26 \text{ V}, I_O = 250 \text{ mA}$		20	75	mV	
Ripple rejection	$V_1 = 13 \text{ V to } 23 \text{ V}, f = 120 \text{ Hz}$	50	55		dB	
Output regulation voltage	$I_O = 5$ mA to 750 mA		30	100	mV	
Dropout voltage	$I_O = 500 \text{ mA}$			0.5	V	
Dropout voltage	I <sub>O</sub> = 750 mA			0.6	V	
Output noise voltage	f = 10 Hz to 100 kHz		1000		μV	
Bias current	I <sub>O</sub> = 750 mA		60	75		
	$I_O = 10 \text{ mA}$		·	5	mA	

<sup>(1)</sup> Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF tantalum capacitor on the output, with equivalent series resistance within the guidelines shown in Figure 1.

# TL750M12 ELECTRICAL CHARACTERISTICS(1)

 $V_1 = 14 \text{ V}$ ,  $I_0 = 300 \text{ mA}$ ,  $T_1 = 25^{\circ}\text{C}$  (unless otherwise noted)

DADAMETED	TEGT COMPLTICATE	TI	TL750M12				
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
Output valtage		11.88	12	12.12	V		
Output voltage	$T_J = 0$ °C to 125°C	11.76		12.24	V		
Input voltage regulation	$V_{I} = 14 \text{ V to } 19 \text{ V}, I_{O} = 250 \text{ mA}$		15	43	\/		
	$V_I$ = 13 V to 26 V, $I_O$ = 250 mA		20	78	mV		
Ripple rejection	V <sub>I</sub> = 13 V to 23 V, f = 120 Hz	50	55		dB		
Output regulation voltage	I <sub>O</sub> = 5 mA to 750 mA		30	120	mV		
Dronout voltage	I <sub>O</sub> = 500 mA			0.5	V		
Dropout voltage	I <sub>O</sub> = 750 mA			0.6	V		
Output noise voltage	f = 10 Hz to 100 kHz		1000		μV		
Diag gurrant	I <sub>O</sub> = 750 mA		60	75	A		
Bias current	I <sub>O</sub> = 10 mA			5	mA		

<sup>(1)</sup> Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF tantalum capacitor on the output, with equivalent series resistance within the guidelines shown in Figure 1.



#### PARAMETER MEASUREMENT INFORMATION

The TL750Mxx is a low-dropout regulator. This means that the capacitance loading is important to the performance of the regulator because it is a vital part of the control loop. The capacitor value and the equivalent series resistance (ESR) both affect the control loop and must be defined for the load range and the temperature range. Figure 1 and Figure 2 can establish the capacitance value and ESR range for the best regulator performance.

Figure 1 shows the recommended range of ESR for a given load with a 10- $\mu$ F capacitor on the output. This figure also shows a maximum ESR limit of 2  $\Omega$  and a load-dependent minimum ESR limit.

For applications with varying loads, the lightest load condition should be chosen because it is the worst case. Figure 2 shows the relationship of the reciprocal of ESR to the square root of the capacitance with a minimum capacitance limit of 10  $\mu$ F and a maximum ESR limit of 2  $\Omega$ . This figure establishes the amount that the minimum ESR limit shown in Figure 1 can be adjusted for different capacitor values.

For example, where the minimum load needed is 200 mA, Figure 1 suggests an ESR range of 0.8  $\Omega$  to 2  $\Omega$  for 10  $\mu$ F. Figure 2 shows that changing the capacitor from 10  $\mu$ F to 400  $\mu$ F can change the ESR minimum by greater than 3/0.5 (or 6). Therefore, the new minimum ESR value is 0.8/6 (or 0.13  $\Omega$ ). This allows an ESR range of 0.13  $\Omega$  to 2  $\Omega$ , achieving an expanded ESR range by using a larger capacitor at the output. For better stability in low-current applications, a small resistance placed in series with the capacitor (see Table 1) is recommended, so that ESRs better approximate those shown in Figure 1 and Figure 2.

Table 1. Compensation for Increased Stability at Low Currents

MANUFACTUR ER	CAPACITANCE	ESR TYP	PART NUMBER	ADDITIONAL RESISTANCE	Applied Load Current	△IL
AVX	15 μF	0.9 Ω	TAJB156M010S	1 Ω	Load	
KEMET	33 μF	0.6 Ω	T491D336M010 AS	0.5 Ω	Voltage	

# OUTPUT CAPACITOR EQUIVALENT SERIES RESISTANCE (ESR)

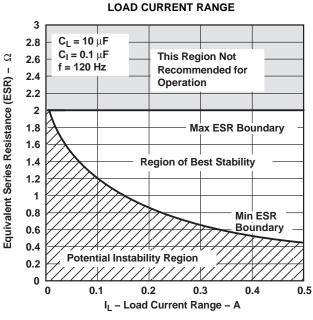


Figure 1.

# STABILITY vs EQUIVALENT SERIES RESISTANCE (ESR)

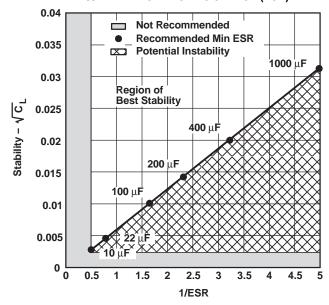


Figure 2.



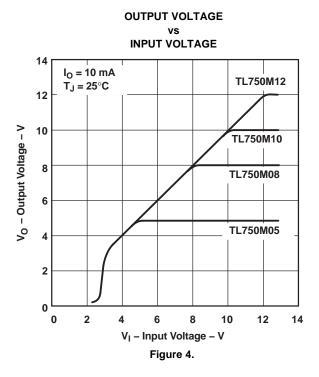
#### **TYPICAL CHARACTERISTICS**

#### **Table 2. Table of Graphs**

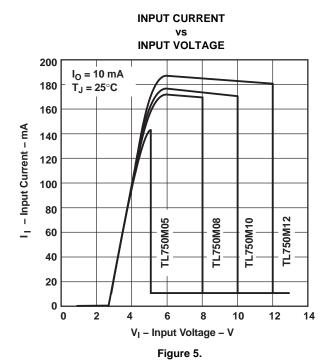
		FIGURE			
Transient input voltage vs Time		3			
Output voltage vs Input voltage		4			
land the summer to the land to the sum	I <sub>O</sub> = 10 mA	5			
Input current vs Input voltage	I <sub>O</sub> = 100 mA	6			
Dropout voltage vs Output current	Dropout voltage vs Output current				
Quiescent voltage vs Output current		8			
Load transient response		9			
Line transient response		10			

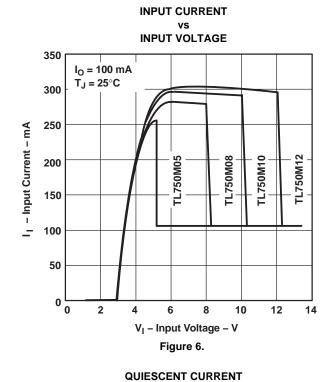
# TRANSIENT INPUT VOLTAGE TIME 60 $T_J = 25^{\circ}C$ $V_I = 14 V + 46e^{(-t/0.230)}$ for $t \ge 5$ ms 50 V<sub>I</sub> - Transient Input Voltage - V 40 30 t<sub>r</sub> = 1 ms 20 10 0 100 0 200 300 400 500 600 t - Time - ms

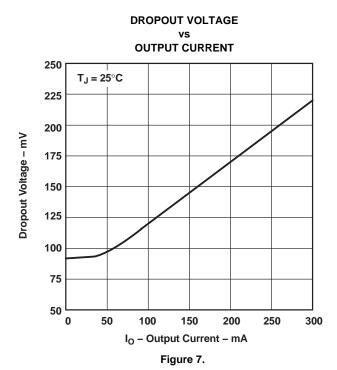
Figure 3.

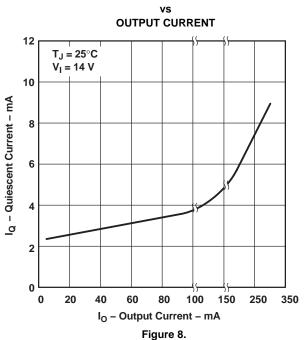




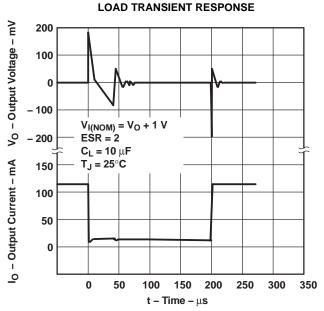














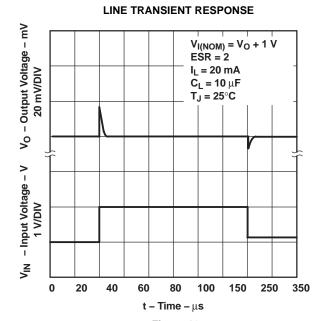


Figure 10.





4-Feb-2021

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	(.,		J		,	(=)	(6)	(0)		()	
TL750M05CKCSE3	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	TL750M05C	Samples
TL750M05CKTTR	ACTIVE	DDPAK/ TO-263	KTT	3	500	RoHS & Green	SN	Level-3-245C-168 HR	0 to 125	TL750M05C	Samples
TL750M05CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	50M05C	Samples
TL750M08CKCSE3	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	TL750M08C	Samples
TL750M08CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	50M08C	Samples
TL750M10CKCSE3	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	TL750M10C	Samples
TL750M10CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	50M10C	Samples
TL750M12CKCSE3	ACTIVE	TO-220	KCS	3	50	RoHS & Green	SN	N / A for Pkg Type	0 to 125	TL750M12C	Samples
TL750M12CKVURG3	ACTIVE	TO-252	KVU	3	2500	RoHS & Green	SN	Level-3-260C-168 HR	0 to 125	50M12C	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



# PACKAGE OPTION ADDENDUM

4-Feb-2021

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF TL750M:

Automotive: TL750M-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# PACKAGE MATERIALS INFORMATION

www.ti.com 24-Apr-2020

# TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL750M05CKTTR	DDPAK/ TO-263	KTT	3	500	330.0	24.4	10.8	16.3	5.11	16.0	24.0	Q2
TL750M05CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
TL750M08CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
TL750M10CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
TL750M12CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2

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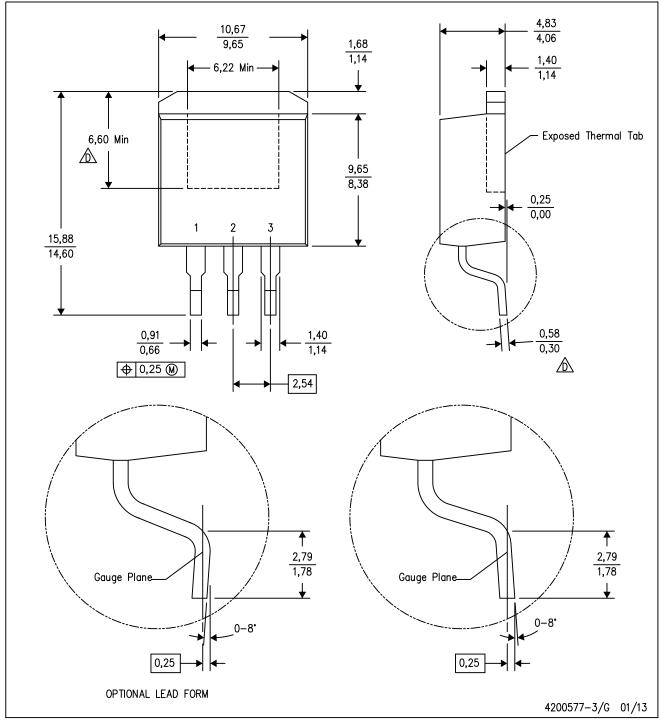


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL750M05CKTTR	DDPAK/TO-263	KTT	3	500	340.0	340.0	38.0
TL750M05CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
TL750M08CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
TL750M10CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
TL750M12CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0

# KTT (R-PSFM-G3)

# PLASTIC FLANGE-MOUNT PACKAGE



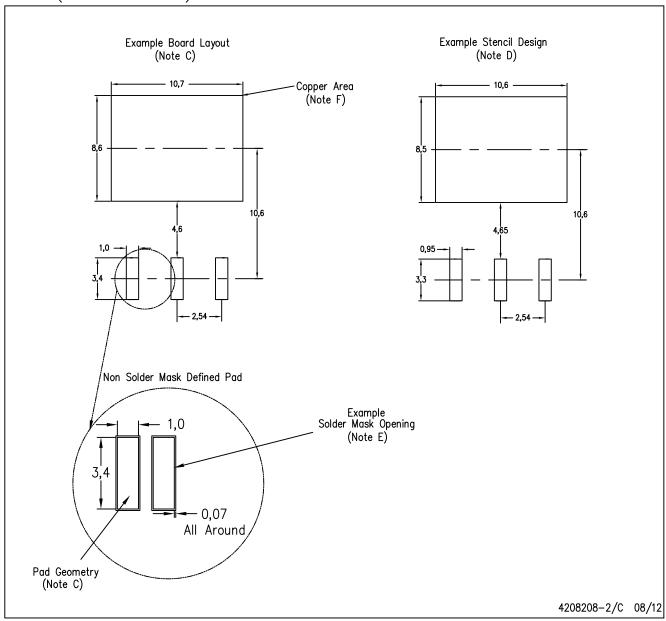
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0.005 (0,13) per side.
- ⚠ Falls within JEDEC T0—263 variation AA, except minimum lead thickness and minimum exposed pad length.



# KTT (R-PSFM-G3)

# PLASTIC FLANGE-MOUNT PACKAGE



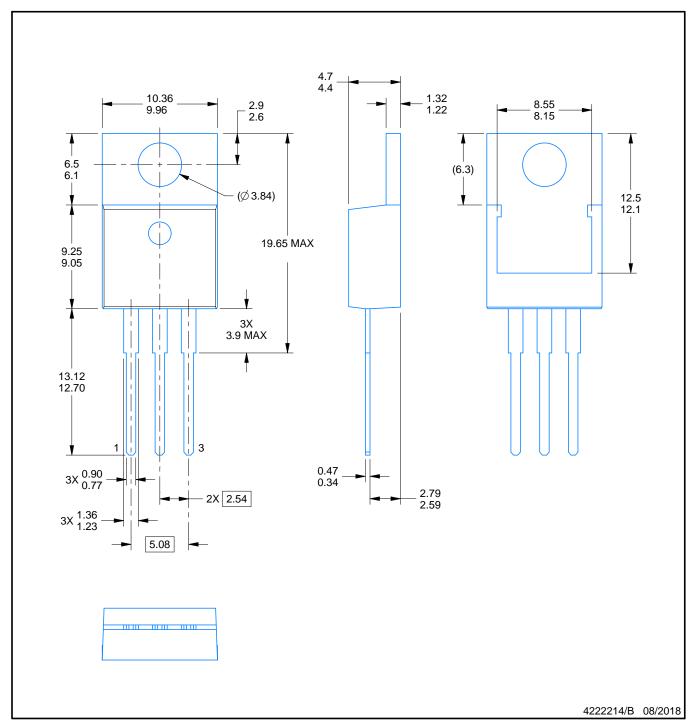
NOTES: A.

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.

  Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
- F. This package is designed to be soldered to a thermal pad on the board. Refer to the Product Datasheet for specific thermal information, via requirements, and recommended thermal pad size. For thermal pad sizes larger than shown a solder mask defined pad is recommended in order to maintain the solderable pad geometry while increasing copper area.







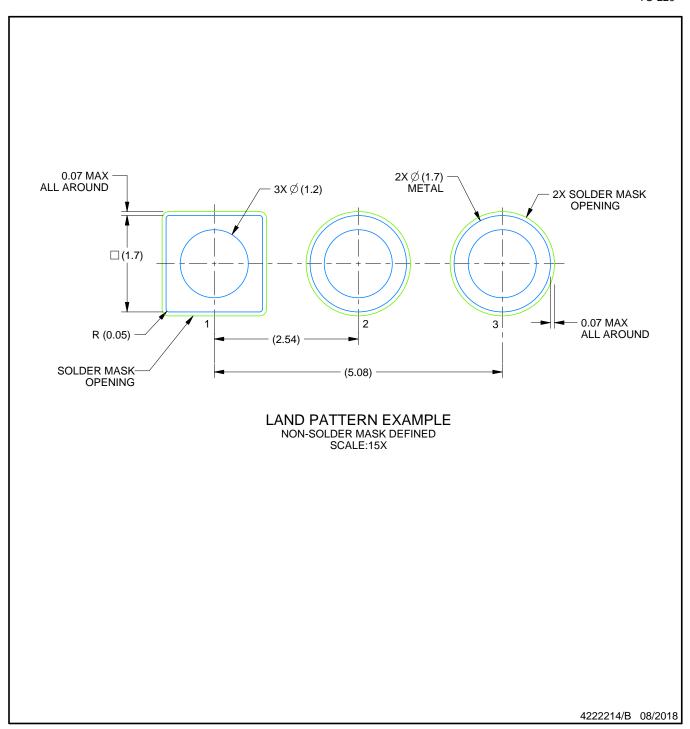
#### NOTES:

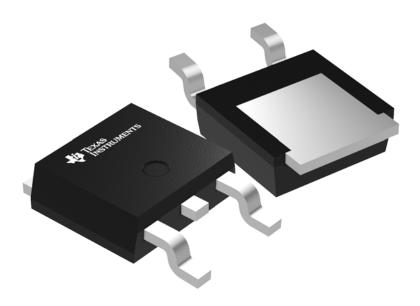
- 1. Dimensions are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Reference JEDEC registration TO-220.





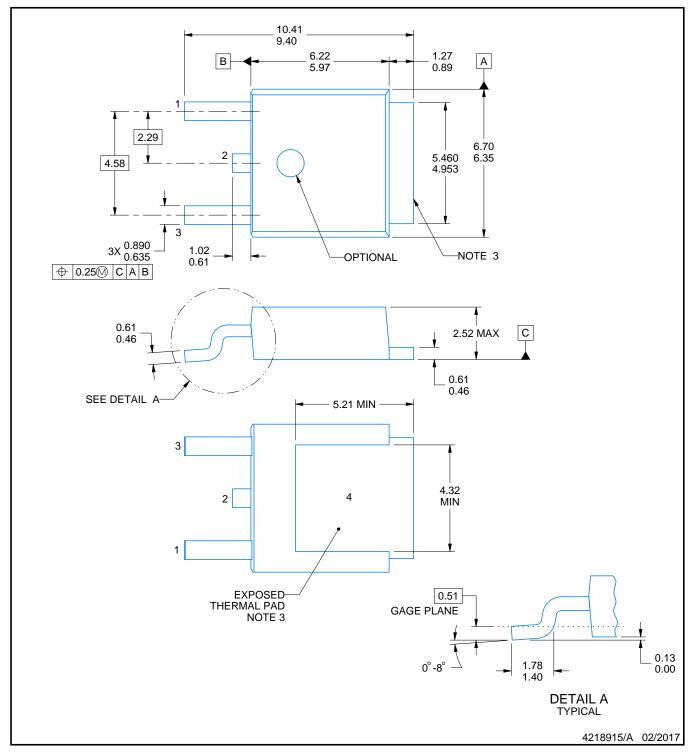


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4205521-2/E







#### NOTES:

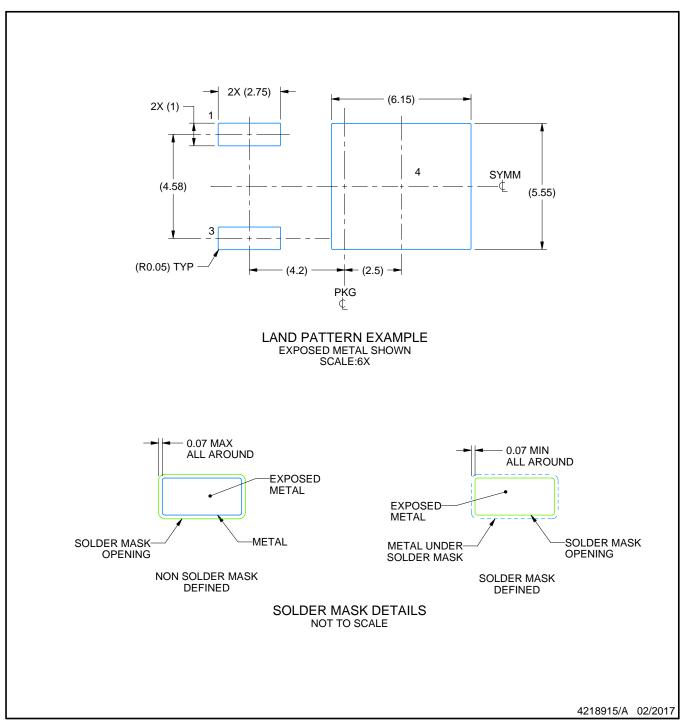
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Shape may vary per different assembly sites.

  4. Reference JEDEC registration TO-252.

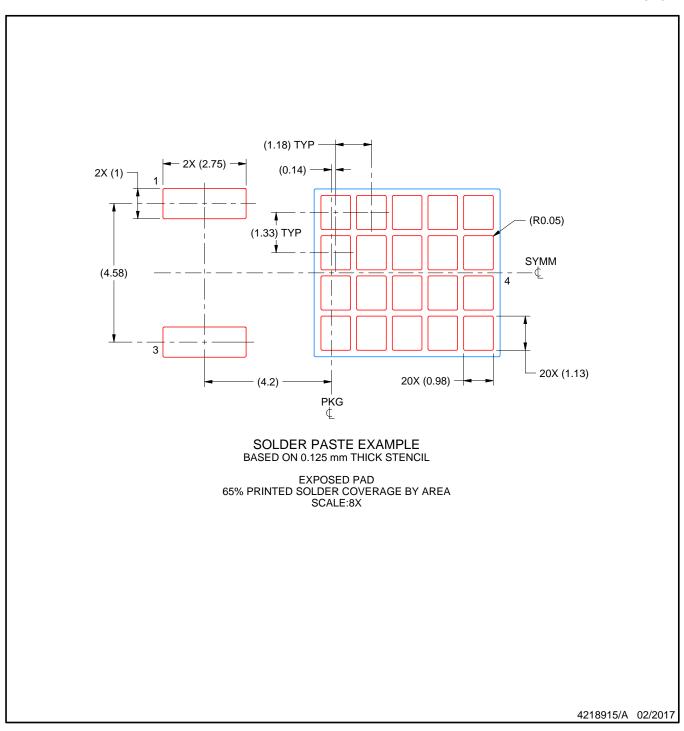




NOTES: (continued)

- 5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).
- 6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)



<sup>7.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.

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